New Product

VISHAY.

Sub-Ω, Low Voltage, SPDT Analog Switches with Over Current Protection

DESCRIPTION

The DG2520/DG2521 are low-voltage single single-pole/ double-throw monolithic CMOS analog switches. Designed to operate from 1.8 V to 5.5 V power supply, the DG2520/ DG2521 provide low on-resistance (0.8 Ω), excellent onresistance matching (0.06 Ω) and flatness (0.2 Ω) over the entire signal range.

The DG2520/DG2521 offers the advantage of high linearity that reduces signal distortion, making ideal for audio, video, and USB signal routing applications. Additionally, the DG2520/DG2521 are 1.6 V logic compatible within the full operation voltage range.

The DG2520/DG2521 offer over current protection. The protection circuitry activates when voltage drop across switch reaches 0.6 V typical. A direct/sustained short circuit will cause the switch to pulse on for typically less than 1 μ s, then turn off. The switch turns on after 5 ms. If the short circuit condition remains, the switch turns off and on to produce a pulsed output. The current limiting circuitry is not instantaneous, and therefore will not activate when the output charges a small 0.1 μ F capacitor.

Built on Vishay Siliconix's proprietary sub-micron high-density process, the DG2520/DG2521 brings low power consumption at the same time as reduces PCB spacing with the TSOP6 package

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations. For analog switching products manufactured with 100 % matte tin device termination, the lead (Pb)-free "- E3" suffix is being used as a designator.

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



FEATURES

- 1.8 to 5.5 V Single Supply Operation
- Low Ron: Typical 0.4 Ω at 4.5 V
- + 1.6 V Logic Compatible
- Over Current Protection

BENEFITS

- High Linearity
- Low Power Consumption
- High Bandwidth
- Full Rail Signal Swing Range

APPLICATIONS

- USB/UART Signal Switching
- Audio/Video Switching
- Cellular Phone
- Media Players
- Modems
- Hard Drives
- PCMCIA

TRUTH TABLE				
Logic	NC	NO		
0	ON	OFF		
1	OFF	ON		

ORDERING INFORMATION					
Temp Range	Package	Part Number			
- 40 to 85 °C	TSOP-6	DG2520DV-T1-E3			
	130F-0	DG2521DV-T1-E3			

DEVICE MARKING:

DG2520DV = F9xxx DG2521DV = F0xxx



DG2520/DG2521

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ABSOLUTE MAXIMUM RATINGS

Reference to GND		Limit	Unit	
V+		- 0.3 to + 6	V	
IN, COM, NC, NO ^a		- 0.3 to (V+ + 0.3)	v	
Continuous Current (Any terminal)		± 50	mA	
Peak Current (Pulsed at 1 ms, 10 % duty cycle)		± 200		
Storage Temperature (D Suffix)		- 65 to 150	°C	
Power Dissipation (Packages) ^b	TSOP-6 ^c	570	mW	

Notes:

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings. b. All leads welded or soldered to PC Board. c. Derate 7 mW/°C above 70 °C.

Parameter		Test Conditions Otherwise Unless Specified		Limits - 40 to 85 °C				
	Symbol	$V + = 3 V, \pm 10 \%, V_{IN} = 0.4$	or 1.8 V ^e	Temp ^a	Min ^c	Тур ^ь	Max ^c	Unit
Analog Switch						•	•	
Analog Signal Range ^d	V _{NO,} V _{NC,} V _{COM}			Full	0		V+	V
On-Resistance	r _{ON}	$V + = 2.7 V, V_{COM} = 1$ $I_{NO/NC} = 100 mA$		Room Full		0.6	1.0 1.2	
r _{ON} Flatness	r _{ON} Flatness	$V_{+} = 2.7 V, V_{COM} = 0, 0.75, 1.5 V$ $I_{NO/NC} = 100 mA$ $V_{+} = 2.7 V, V_{COM} = 1.5 V$ $I_{NO/NC} = 100 mA$		Room Full		0.12	0.16 0.18	Ω
r _{ON} Match Between Channels	Δr_{ON}			Full			0.06	
Digital Control								
Input High Voltage ^d	V _{INH}			Full	1.8			
Input Low Voltage	V _{INL}			Full			0.4	V
Input Capacitance	CIN			Full		7		pF
Input Current	I _{INL or} I _{INH}			Full	- 1		1	μA
Dynamic Characteristics								-
Turn-On Time DG2520	t _{ON}	V+ = 2.7 V, V _{NO} or V _{NC} = 1.5 V R _L = 50 Ω , C _L = 35 pF		Room Full		30	45 60	
Turn-Off Time DG2520	t _{OFF}			Room Full		10	17 22	
Break-Before-Make Time DG2520	t _{bbm}	$V_{NO} \text{ or } V_{NC}$ = 1.5 V, R_L = 50 Ω , C_L = 35 pF		Full	1	25		ns
Turn-On Time DG2521	t _{ON}	V+ = 2.7 V, V _{NO} or V _{NC} = 1.5 V R _L = 50 Ω , C _L = 35 pF		Room Full		18	25 40	- 115
Turn-Off Time DG2521	t _{OFF}			Room Full		25	45 55	
Make-Before-Break Time DG2521	t _{mbb}	V_{NO} or V_{NC} = 1.5 V, R_L = 50 Ω , C_L = 35 pF		Full	1	10		
Charge Injection ^d	Q	$C_L = 1 \text{ nF}, V_{GEN} = 0 \text{ V}, R_{GEN} = 0 \Omega$		Room		115		рС
- 3 dB Bandwidth	BW	0 dBm, $C_L = 5 pF$, $R_L =$		Room		40		MHz
Off-Isolation ^d	OIRR	$P_{1} = 50.0 C_{2} = 5 nE$	f = 1 MHz	Room		- 51		dB
Crosstalk ^d	X _{TALK}	= 00 32, OL= 0 pr	f = 1 MHz	Room		- 57		
N_O , N_C Off Capacitance ^d	C _{NO(off)} C _{NC(off)}	V _{IN} = 0 or V+, f = 1 MHz		Room Room		50 50		-
	C _{NO(on)}			Room		160		– pF –
Channel On Capacitance ^d	C _{NC(on)}			Room		160		
Power Supply	<u>\-</u> /							
Power Supply Current	l+	V _{IN} = 0 or V+		Full			20	μA

Notes: a. Room = 25 °C, Full = as determined by the operating suffix. b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing. c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet

d. Guarantee by design, nor subjected to production test. e. V_{IN} = input voltage to perform proper function. f. Guaranteed by 5 V leakage testing, not production tested.



DG2520/DG2521

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		Test Conditions Otherwise Unless Specified V+ = 5 V, \pm 10 %, V _{IN} = 0.8 or 2.4 V ^e		-	Limits - 40 to 85 °C		
Parameter	Symbol			Min ^c	Тур ^b	Max ^c	Unit
Analog Switch			I	•	•	•	
Analog Signal Range ^d	V _{NO,} V _{NC,} V _{COM}		Full	0		V+	V
On-Resistance	r _{ON}	V+ = 4.5 V, V _{COM} = 3.5 V, I _{NO/NC} = 100 r	i un		0.4	0.8 1.0	
r _{ON} Flatness	r _{ON} Flatness	$V_{+} = 4.5 V, V_{COM} = 0, 1, 2 V, I_{NO/NC} = 100$	mA Room Full		0.15	0.2 0.22	Ω
r _{ON} Match Between Channels	Δr_{ON}	$V_{+} = 4.5 V, V_{COM} = 3.5 V$ $I_{NO/NC} = 100 mA$	Full			0.06	
Switch Off Leakage Current	I _{NO(off),} I _{NC(off)}	V+ = 5.5 V,	Room Full	- 2 - 20		2 20	nA
	I _{COM(off)}	$V_{NO}, V_{NC} = 1 \text{ V}/4.5 \text{ V}, V_{COM} = 4.5 \text{ V}/1$	V Room Full	- 2 - 20		2 20	
Channel On Leakage Current	I _{COM(on)}	$V_{+} = 5.5 \text{ V}, \text{ V}_{\text{NO}}, \text{ V}_{\text{NC}} = \text{V}_{\text{COM}} = 1 \text{ V}/4.5 \text{ V}$		- 2 - 20		2 20	1
Digital Control				•		•	
Input High Voltage ^d	V _{INH}		Full	2.4			
Input Low Voltage	V _{INL}		Full			0.8	V
Input Capacitance	C _{IN}		Full		10		pF
Input Current	I _{INL or} I _{INH}		Full	- 1		1	μA
Overcurrent-Protection Current Threshold			Room		1.7		А
Dynamic Characteristics						•	_
Turn-On Time DG2520	t _{ON}		Room		25	35	Т
	ON	$V_{+} = 4.5 V$, V_{NO} or $V_{NC} = 3 V$	Full Room			40	
Turn-Off Time DG2520	t_{OFF}	R _L = 50 Ω, C _L = 35 pF			8	15 20	
Break-Before-Make Time DG2520	t _{bbm}	V_{NO} or V_{NC} = 3 V, R_L = 50 Ω , C_L = 35 p	F Full	1	15		ns
Turn-On Time DG2521	t _{ON}	V+ = 4.5 V, V _{NO} or V _{NC} = 3 V $R_L = 50 \Omega$, $C_L = 35 pF$ V _{NO} or V _{NC} = 3 V, $R_L = 50 \Omega$, $C_L = 35 pF$			12	25 35	115
Turn-Off Time DG2521	t _{OFF}				20	35 45	
Make-Before-Break Time DG2521	t _{mbb}			1	12		
Charge Injection ^d	Q	$C_L = 1 \text{ nF}, V_{GEN} = 0 \text{ V}, R_{GEN} = 0 \Omega$	Room		224		рС
- 3 dB Bandwidth	BW	$0 \text{ dBm}, \text{ C}_{\text{L}} = 5 \text{ pF}, \text{ R}_{\text{L}} = 50 \Omega$	Room		40		MH
Off-Isolation ^d	OIRR	$R_L = 50 \Omega, C_L = 5 pF$ $f = 1 N$			- 51		dB
Crosstalk ^d	X _{TALK}	f = 1 N			- 57		
Source Off Capacitance ^d	C _{NO(off)}	4	Room Room		50 50		_
	C _{NC(off)} C _{NO(on)}	f = 1 MHz			160		pF
Channel On Capacitance ^d	C _{NO(on)}		Room Room		160		1
Power Supply							
Power Supply Range	V+			1.8		5.5	V
Power Supply Current	l+	V _{IN} = 0 or V+	Full			22	μA

Notes:

Notes: a. Room = 25 °C, Full = as determined by the operating suffix. b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing. c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet d. Guarantee by design, nor subject to production test. e. V_{IN} = input voltage to perform proper function. f. Guaranteed by 5 V leakage testing, not production tested.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



VISHA



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TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted





Frequency (Hz) Off Isolation, Crosstalk and Insertion Loss vs. Frequency



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Charge Injection vs. Analog Voltage, DG2520





$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$

Figure 1. Switching Time





Charge Injection vs. Analog Voltage, DG2521



Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.



C_L (includes fixture and stray capacitance)

Figure 2. Break-Before-Make Interval





DG2520/DG2521

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Figure 3. Make-Before-Break Interval





IN depends on switch configuration: input polarity determined by sense of switch.





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